

DTC144VUA / DTC144VKA / DTC144VSA

Transistors

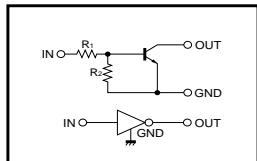
Digital transistor (built-in resistors)

DTC144VUA / DTC144VKA / DTC144VSA

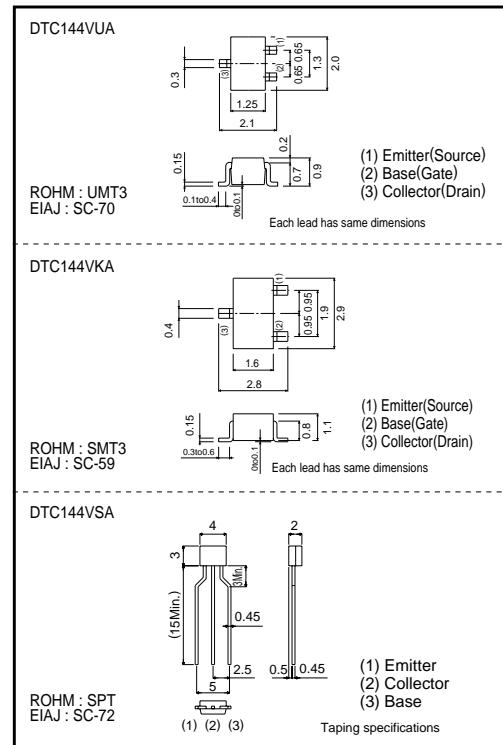
●Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors.
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input, and parasitic effects are almost completely eliminated.
- 3) Only the on / off conditions need to be set for operation, making device design easy.
- 4) Higher mounting densities can be achieved.

●Equivalent circuit



●External dimensions (Units : mm)



●Absolute maximum ratings ($T_a = 25^\circ\text{C}$)

| Parameter | Symbol | Limits | Unit |
|-----------------------|--------------------|----------|------|
| Supply voltage | V_{cc} | 50 | V |
| Input voltage | V_i | -15~+40 | V |
| Output current | I_o | 30 | mA |
| | $I_c(\text{Max.})$ | 100 | |
| Power dissipation | P_d | 200 | mW |
| DTC144VUA / DTC144VKA | | 300 | |
| DTC144VSA | | 150 | °C |
| Junction temperature | T_j | -55~+150 | °C |
| Storage temperature | T_{stg} | -55~+150 | °C |

●Packaging, marking and packaging specifications

| Type | DTC144VUA | DTC144VKA | DTC144VSA |
|------------------------------|-----------|-----------|-----------|
| Package | UMT3 | SMT3 | SPT |
| Marking | 166 | E66 | - |
| Packaging code | T106 | T146 | TP |
| Basic ordering unit (pieces) | 3000 | 3000 | 5000 |

●Electrical characteristics ($T_a = 25^\circ\text{C}$)

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions |
|----------------------|---------------------|------|------|------|---------------|---|
| Input voltage | $V_{i(\text{off})}$ | - | - | 1 | V | $V_{cc}=5\text{V}$, $I_o=100\mu\text{A}$ |
| | $V_{i(\text{on})}$ | 6 | - | - | | $V_{cc}=0.3\text{V}$, $I_o=2\text{mA}$ |
| Output voltage | $V_{o(\text{on})}$ | - | 0.1 | 0.3 | V | $I_o=10\text{mA}$, $I_i=0.5\text{mA}$ |
| Input current | I_i | - | - | 0.16 | mA | $V_i=5\text{V}$ |
| Output current | $I_o(\text{off})$ | - | - | 0.5 | μA | $V_{cc}=50\text{V}$, $V_i=0\text{V}$ |
| DC current gain | G_i | 33 | - | - | | $I_o=5\text{mA}$, $V_o=5\text{V}$ |
| Input resistance | R_i | 32.9 | 47 | 61.1 | k Ω | - |
| Resistance ratio | R_2/R_1 | 0.17 | 0.21 | 0.26 | - | - |
| Transition frequency | f_T | - | 250 | - | MHz | $V_{ce}=10\text{V}$, $I_e=-5\text{mA}$, $f=100\text{MHz}$ |

* Transition frequency of the device.

ROHM